

## 2N5902-2N5909

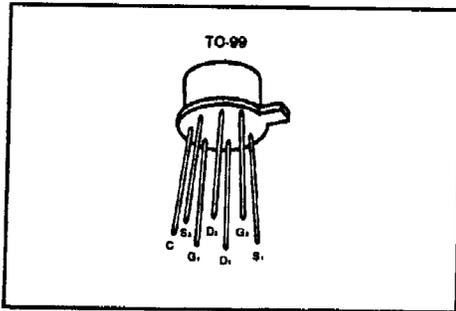
### Monolithic Dual N-Channel JFET

### General Purpose Amplifier

#### FEATURES

- Tight Tracking
- Good Matching

#### PIN CONFIGURATION



#### ABSOLUTE MAXIMUM RATINGS

( $T_A = 25^\circ\text{C}$  unless otherwise specified)

Gate-Drain or Gate-Source Voltage (Note 1)	-40V
Gate Current (Note 1)	10mA
Storage Temperature Range	$-65^\circ\text{C}$ to $+200^\circ\text{C}$
Operating Temperature Range	$-55^\circ\text{C}$ to $+150^\circ\text{C}$
Lead Temperature (Soldering, 10sec)	$+300^\circ\text{C}$

	One Side	Both Sides
Power Dissipation	367mW	500mW
Derate above $25^\circ\text{C}$	3mW/ $^\circ\text{C}$	4mW/ $^\circ\text{C}$

NOTE: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

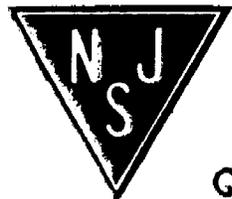
#### ORDERING INFORMATION

TO-99
2N5902
2N5903
2N5904
2N5905
2N5906
2N5907
2N5908
2N5909

#### ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise specified)

Symbol	Parameter	Test Conditions	2N5902-6		2N5903-7		2N5904-8		2N5905-9		Units
			Min	Max	Min	Max	Min	Max	Min	Max	
$ I_{G1} - I_{G2} $	Differential Gate Current	$V_{DG} = 10V$ , $I_D = 30\mu A$ , $T_A = 125^\circ\text{C}$	2N5902-5	2.0	2.0	2.0	2.0	2.0	2.0	nA	
$I_{DSS1}$ $I_{DSS2}$	Saturation Drain Current Ratio	$V_{DS} = 10V$ , $V_{GS} = 0$	0.95	1	0.95	1	0.95	1	0.95	1	
$g_{fs1}$ $g_{fs2}$	Transconductance Ratio	$f = 1\text{kHz}$	0.97	1	0.97	1	0.95	1	0.95	1	
$ V_{GS1} - V_{GS2} $	Differential Gate-Source Voltage			5	5	10	15	mV			
$\Delta  V_{GS1} - V_{GS2} $ $\Delta T$	Gate-Source Voltage Differential Drift (Measured at end points $T_A$ and $T_B$ )	$V_{DG} = 10V$ , $I_D = 30\mu A$	$T_A = 25^\circ\text{C}$ $T_B = 125^\circ\text{C}$	5	10	20	40	$\mu V/^\circ\text{C}$			
$ g_{os1} - g_{os2} $	Differential Output Conductance	$f = 1\text{kHz}$	0.2	0.2	0.2	0.2	$\mu S$				

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## 2N5902-2N5909

### ELECTRICAL CHARACTERISTICS (Continued) ( $T_A = 25^\circ\text{C}$ unless otherwise specified)

Symbol	Parameter	Test Conditions	2N5902-5		2N5906-9		Units		
			Min	Max	Min	Max			
$I_{GSS}$	Gate Reverse Current	$V_{GS} = -20\text{V}, V_{DS} = 0$ $T_A = 125^\circ\text{C}$		-6		-2	pA		
				-10		-5	nA		
$BV_{GSS}$	Gate-Source Breakdown Voltage	$I_G = -1\mu\text{A}, V_{DS} = 0$	-40		-40		V		
$V_{GS(off)}$	Gate-Source Cutoff Voltage	$V_{DS} = 10\text{V}, I_D = 1\text{nA}$	-0.6	-4.5	-0.8	-4.5			
$V_{GS}$	Gate Source Voltage	$V_{DG} = 10\text{V}, I_D = 30\mu\text{A}$		-4		-4			
$I_G$	Gate Operating Current	$T_A = 125^\circ\text{C}$		-3		-1	pA		
				-3		-1	nA		
$I_{DSS}$	Saturation Drain Current	$f = 1\text{kHz}$	30	500	30	500	$\mu\text{A}$		
$g_{fs}$	Common-Source Forward Transconductance	$V_{DS} = 10\text{V}, V_{GS} = 0$		70	250	70	250	$\mu\text{S}$	
$g_{os}$	Common-Source Output Conductance				5		5		
$C_{iss}$	Common-Source Input Capacitance	$V_{DS} = 10\text{V}, V_{GS} = 0$ (Note 1)	$f = 1\text{MHz}$			3		pF	
$C_{rss}$	Common-Source Reverse Transfer Capacitance					1.5			1.5
$g_{fs}$	Common-Source Forward Transconductance	$V_{DG} = 10\text{V}, I_D = 30\mu\text{A}$	$f = 1\text{kHz}$		50	150	50	150	$\mu\text{S}$
$g_{os}$	Common-Source Output Conductance					1		1	
$\bar{e}_n$	Equivalent Short Circuit Input Noise Voltage (Note 1)	$V_{DS} = 10\text{V}, V_{GS} = 0$			0.2		0.1	$\frac{\mu\text{V}}{\sqrt{\text{Hz}}}$	
NF	Spot Noise Figure (Note 1)		$f = 100\text{Hz}$ $R_G = 10\text{M}\Omega$		3		1	dB	

NOTE 1: For design reference only, not 100% tested.